## 2SK2593

## Silicon N-Channel Junction FET

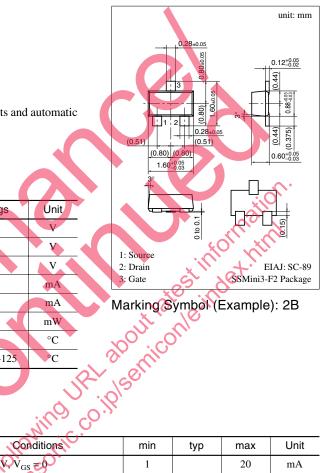
For low-frequency amplification For switching

#### ■ Features

- Low noies, high gain
- High gate to drain voltage V<sub>GDO</sub>
- Mini-type package, allowing downsizing of the sets and automatic insertion through the tape/magazine packing.

### ■ Absolute Maximum Ratings (Ta = 25°C)

Parameter	Symbol	Ratings	Unit	
Drain to Source voltage	V <sub>DSX</sub>	55	V	
Gate to Drain voltage	V <sub>GDO</sub>	-55	V	
Gate to Source voltage	V <sub>GSO</sub>	-55	V	
Drain current	$I_D$	±30	mA	
Gate current	$I_G$	10	mA	
Allowable power dissipation	$P_{\rm D}$	125	mW	
Junction temperature	T <sub>j</sub>	125	°C	
Storage temperature	T <sub>stg</sub>	-55 to +125	°C	



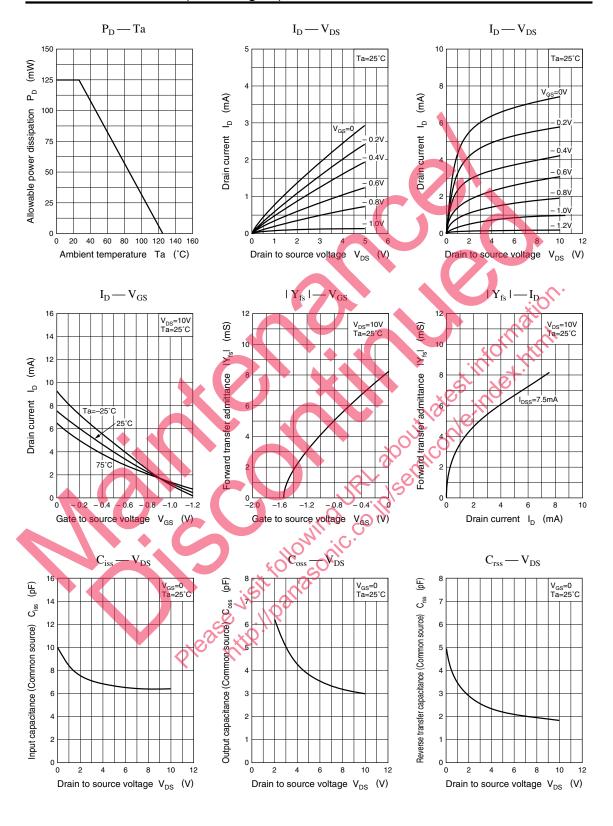
### ■ Electrical Characteristics (Ta = 25°)

Parameter	Symbol	Conditions	min	typ	max	Unit
Drain to Source cut-off current	I <sub>DSS</sub> *	$V_{DS} = 10V, V_{GS} \neq 0$	1		20	mA
Gate to Source leakage current	$I_{GSS}$	$V_{GS} = -30V, V_{DS} = 0$			10	nA
Gate to Drain voltage	V <sub>GDS</sub>	$I_{G} = -100 \mu A, V_{DS} = 0$	55	80		V
Gate to Source cut-off voltage	V <sub>GSC</sub>	$V_{DS} = 10V$ , $I_D = 10\mu A$			-5	V
Forward transfer admittance	YE	$V_{DS} = 10V$ , $I_D = 5mA$ , $f = 1kHz$	2.5	7.5		mS
Input capacitance (Common Source)	C <sub>iss</sub>	$V_{DS} = 10V, V_{GS} = 0, f = 1MHz$		6.5		pF
Reverse transfer capacitance (Common Source)	C <sub>rss</sub>	$\mathbf{v}_{\mathrm{DS}} = 10  \mathbf{v}, \ \mathbf{v}_{\mathrm{GS}} = 0, 1 = 1  \mathrm{MHz}$		1.9		pF
Noise figure	NF	$\begin{aligned} V_{DS} &= 10 V,  V_{GS} = 0,  R_g = 100 k \Omega \\ f &= 100 Hz \end{aligned}$		2.5		dB

#### \* I<sub>DSS</sub> rank classification

Runk	P	Q	R	S
I <sub>DSS</sub> (mA)	1 to 3	2 to 6.5	5 to 12	10 to 20
Marking Symbol	2BP	2BQ	2BR	2BS

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